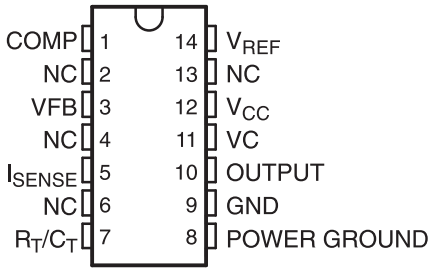
HIGH-PERFORMANCE CURRENT-MODE PWM CONTROLLER

Check for Samples: TL2843B-Q1

FEATURES

- **Qualified for Automotive Applications**
- **Low Start-Up Current (<0.5 mA)**
- **Trimmed Oscillator Discharge Current**
- **Current Mode Operation to 500 kHz**
- **Automatic Feed-Forward Compensation**
- **Latching PWM for Cycle-by-Cycle Current Limiting**
- **Internally Trimmed Reference With Undervoltage Lockout**
- **High-Current Totem-Pole Output Undervoltage Lockout With Hysteresis**
- **Double-Pulse Suppression**

D (SOIC) PACKAGE
(TOP VIEW)



NC – No internal connection

DESCRIPTION

The TL284xB series of control integrated circuits provide the features that are necessary to implement off-line or dc-to-dc fixed-frequency current-mode control schemes, with a minimum number of external components. Internally implemented circuits include an undervoltage lockout (UVLO) and a precision reference that is trimmed for accuracy at the error amplifier input. Other internal circuits include logic to ensure latched operation, a pulse-width modulation (PWM) comparator that also provides current-limit control, and a totem-pole output stage designed to source or sink high-peak current. The output stage, suitable for driving N-channel MOSFETs, is low when it is in the off state.

The TL284xB series are pin compatible with the standard TL284x with the following improvements. The start-up current is specified to be 0.5 mA (max), while the oscillator discharge current is trimmed to 8.3 mA (typ). In addition, during undervoltage lockout conditions, the output has a maximum saturation voltage of 1.2 V while sinking 10 mA (V_{CC} = 5 V).

Major differences between members of these series are the UVLO thresholds and maximum duty-cycle ranges. Typical UVLO thresholds of 16 V (on) and 10 V (off) on the TL2842B and TL2844B devices make them ideally suited to off-line applications. The corresponding typical thresholds for the TL2843B and TL2845B devices are 8.4 V (on) and 7.6 V (off). The TL2842B and TL2843B devices can operate to duty cycles approaching 100%. A duty-cycle range of 0% to 50% is obtained by the TL2844B and TL2845B by the addition of an internal toggle flip-flop, which blanks the output off every other clock cycle.The TL284xB-series devices are characterized for operation from –40°C to 125°C.

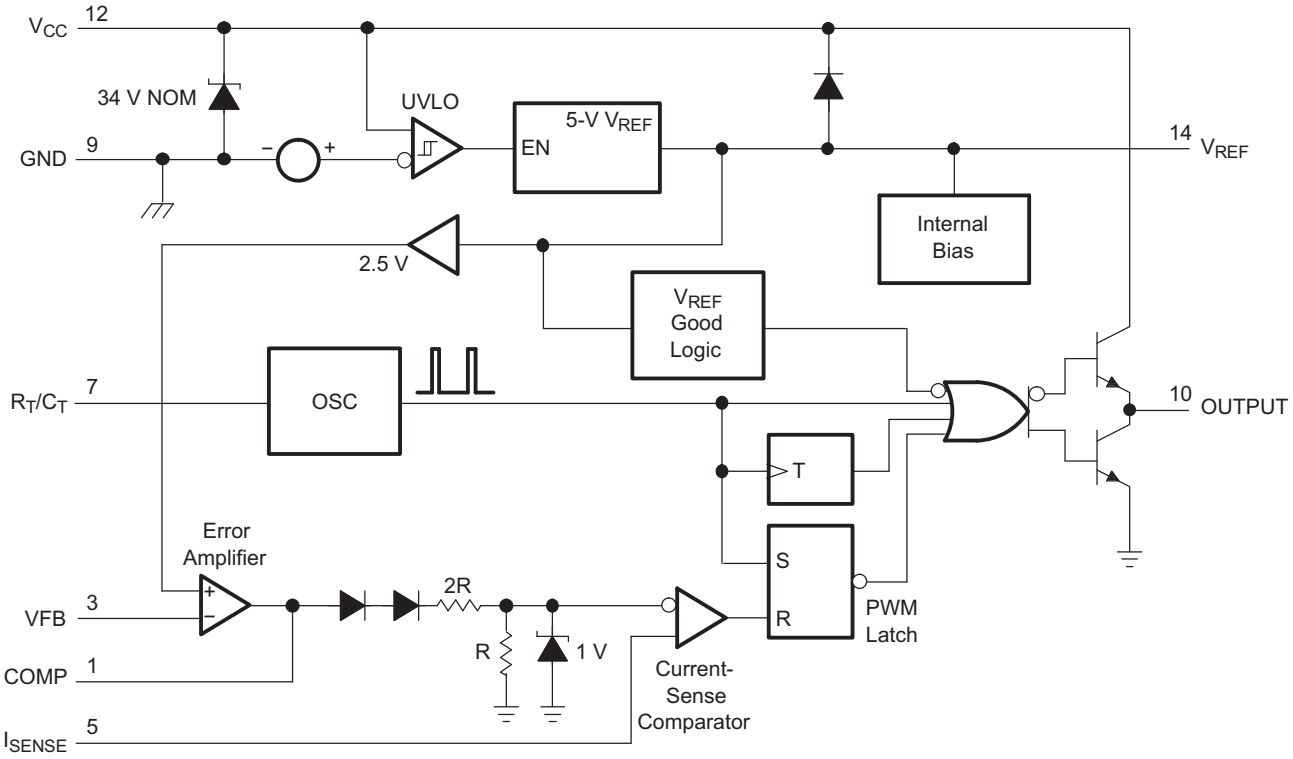
Table 1. ORDERING INFORMATION(1)

T_A	PACKAGE(2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC – D	Reel of 2500	TL2842BQDRQ1	Product Preview
			TL2843BQDRQ1	TL2843BQ
			TL2844BQDRQ1	Product Preview
			TL2845BQDRQ1	Product Preview

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS(1) (2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage	Low impedance source		30	V
		I_{CC} < 30 mA		Self limiting	
V_I	Analog input voltage range	VFB and I_{SENSE}	–0.3	6.3	V
I_{CC}	Supply current			30	mA
I_O	Output current			±1	A
$I_{O(sink)}$	Error amplifier output sink current			10	mA
θ_{JA}	Package thermal impedance(3) (4)	D package		97	°C/W
	Output energy	Capacitive load		5	µJ
T_J	Virtual junction temperature			150	°C
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) All voltages are with respect to the device GND terminal.
(3) Maximum power dissipation is a function of $T_J(max)$, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) – T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	V_{CC}			30	V
		VC(1)			30	
V_I	Input voltage	R_T/C_T	0		5.5	V
		VFB and I_{SENSE}	0		5.5	
V_O	Output voltage	OUTPUT	0		30	V
		POWER GROUND(1)	–0.1		1	
I_{CC}	Supply current, externally limited				25	mA
I_O	Average output current				200	mA
$I_{O(ref)}$	Reference output current				–20	mA
f_{osc}	Oscillator frequency			100	500	kHz
T_A	Operating free-air temperature		–40		125	°C

(1) The recommended voltages for VC and POWER GROUND apply only to the 14-pin D package.

REFERENCE SECTION ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V[1], R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP[2]	MAX	
Output voltage	I_O = 1 mA, T_J = 25°C	4.95	5	5.05	V
Line regulation	V_{CC} = 12 V to 25 V		6	20	mV
Load regulation	I_O = 1 mA to 20 mA		6	25	mV
Average temperature coefficient of output voltage			0.2	0.4	mV/°C
Output voltage, worst-case variation	V_{CC} = 12 V to 25 V, I_O = 1 mA to 20 mA	4.9		5.1	V
Output noise voltage	f = 10 Hz to 10 kHz, T_J = 25°C		50		μV
Output-voltage long-term drift	After 1000 h at T_J = 25°C		5	25	mV
Short-circuit output current		–30	–100	–180	mA

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.

OSCILLATOR SECTION[1] ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V[2], R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP[3]	MAX	
Initial accuracy	T_J = 25°C	49	52	55	kHz
	$T_A = T_{low}$ to T_{high}	48		56	
	T_J = 25°C, R_T = 6.2 kΩ, C_T = 1 nF	225	250	275	
Voltage stability	V_{CC} = 12 V to 25 V		0.2	1	%
Temperature stability			5		%
Amplitude	Peak to peak		1.7		V
Discharge current[4]	T_J = 25°C, R_T/C_T = 2 V	7.8	8.3	8.8	mA
	R_T/C_T = 2 V	7.5		8.8	

(1) Output frequency equals oscillator frequency for the TL2842B and TL2843B. Output frequency is one-half the oscillator frequency for the TL2844B and TL2845B.
(2) Adjust V_{CC} above the start threshold before setting it to 15 V.
(3) All typical values are at T_J = 25°C.
(4) Specified by design. Not production tested.

ERROR-AMPLIFIER SECTION ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
Feedback input voltage	COMP = 2.5 V	2.45	2.5	2.55	V
Input bias current			–0.3	–1	μA
Open-loop voltage amplification	V_O = 2 V to 4 V	65	90		dB
Gain-bandwidth product		0.7	1		MHz
Supply-voltage rejection ratio	V_{CC} = 12 V to 25 V	60	70		dB
Output sink current	VFB = 2.7 V, COMP = 1.1 V	2	6		mA
Output source current	VFB = 2.3 V, COMP = 5 V	–0.5	–0.8		mA
High-level output voltage	VFB = 2.3 V, R_L = 15 kΩ to GND	5	6		V
Low-level output voltage	VFB = 2.7 V, R_L = 15 kΩ to GND		0.7	1.1	V

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.

CURRENT-SENSE SECTION ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
Voltage amplification(3) (4)		2.85	3	3.15	V/V
Current-sense comparator threshold(3)	COMP = 5 V	0.9	1	1.1	V
Supply-voltage rejection ratio(3)	V_{CC} = 12 V to 25 V		70		dB
Input bias current			–2	–10	μA
Delay time to output(5)	VFB = 0 V to 2 V		150	300	ns

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.
(3) Measured at the trip point of the latch, with VFB at 0 V.
(4) Measured between I_{SENSE} and COMP, with the input changing from 0 V to 0.8 V.
(5) Specified by design. Not production tested.

Output Section Electrical Characteristics

V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
High-level output voltage	I_{OH} = –20 mA	13	13.5		V
	I_{OH} = –200 mA	12	13.5		
Low-level output voltage	I_{OL} = 20 mA		0.1	0.4	V
	I_{OL} = 200 mA		1.5	2.2	
Rise time(3)	C_L = 1 nF, T_J = 25°C		50	150	ns
Fall time(3)	C_L = 1 nF, T_J = 25°C		50	150	ns
UVLO saturation(3)	V_{CC} = 5 V, I_{OL} = 1 mA		0.7	1.2	V

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.
(3) Specified by design. Not production tested.

UNDERVOLTAGE-LOCKOUT SECTION ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
Start threshold voltage		7.8	8.4	9	V
Minimum operating voltage after start-up		7	7.6	8.2	V

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.

PULSE-WIDTH MODULATOR SECTION ELECTRICAL CHARACTERISTICS

V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
Maximum duty cycle(3)		94	96	100	%
Minimum duty cycle				0	%

(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.
(3) Specified by design. Not production tested.

SUPPLY VOLTAGE ELECTRICAL CHARACTERISTICS

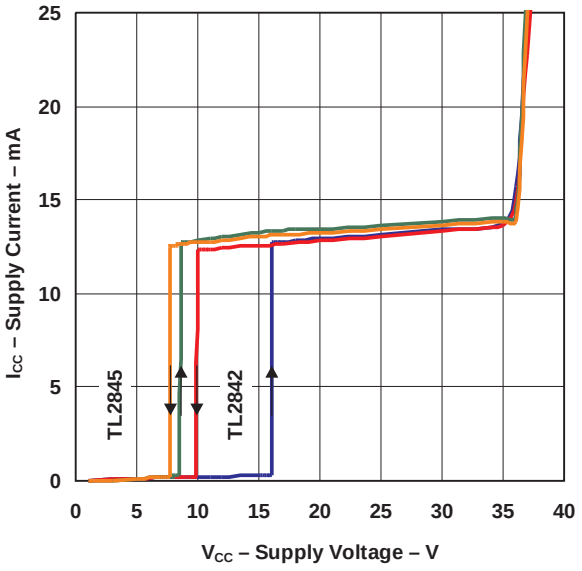
V_{CC} = 15 V(1), R_T = 10 kΩ, C_T = 3.3 nF, over recommended operating free-air temperature range (unless otherwise specified)

PARAMETER	TEST CONDITIONS	TL284xB			UNIT
		MIN	TYP(2)	MAX	
Start-up current			0.3	0.5	mA
Operating supply current	VFB and I_{SENSE} at 0 V		11	17	mA
Limiting voltage	I_{CC} = 25 mA	30	34		V

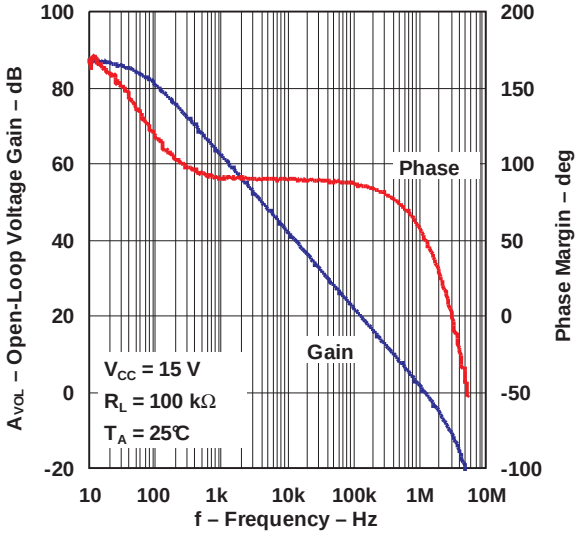
(1) Adjust V_{CC} above the start threshold before setting it to 15 V.
(2) All typical values are at T_J = 25°C.

TYPICAL CHARACTERISTICS

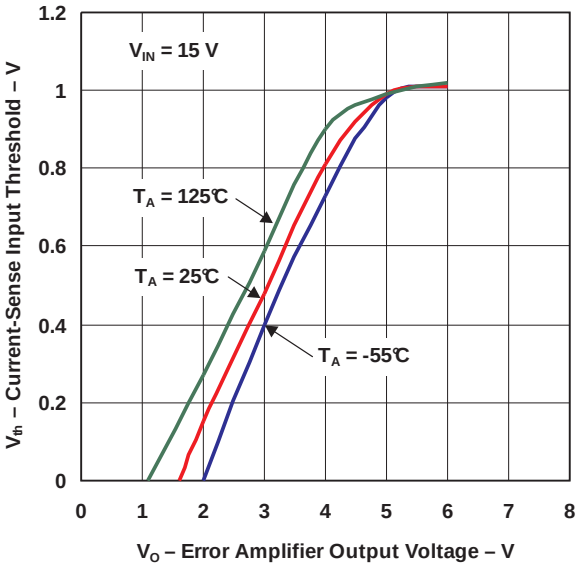
SUPPLY CURRENT vs SUPPLY VOLTAGE



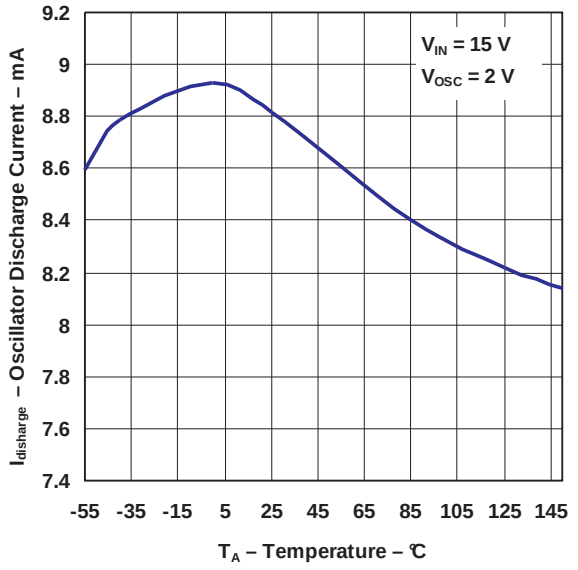
ERROR AMPLIFIER OPEN-LOOP GAIN AND PHASE vs FREQUENCY



CURRENT-SENSE INPUT THRESHOLD vs ERROR AMPLIFIER OUTPUT VOLTAGE

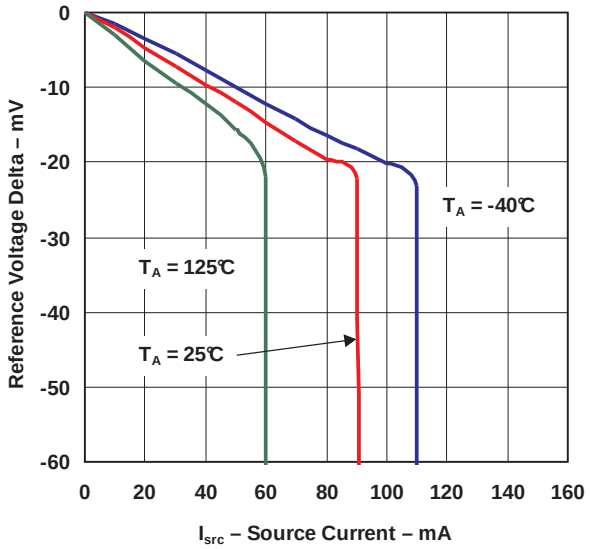


OSCILLATOR DISCHARGE CURRENT vs TEMPERATURE

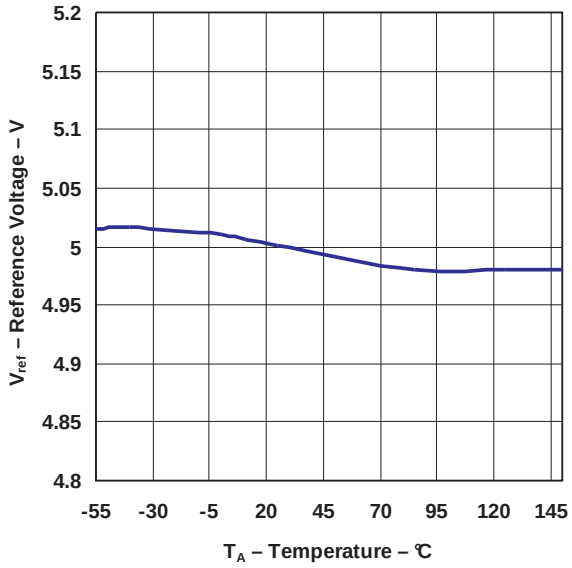


TYPICAL CHARACTERISTICS (continued)

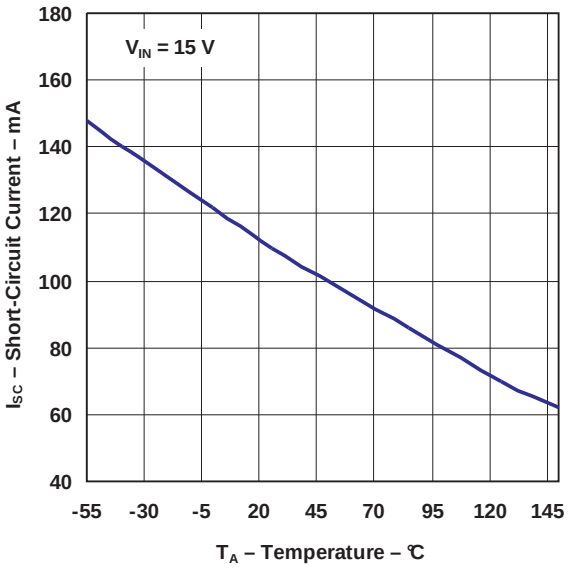
REFERENCE VOLTAGE vs SOURCE CURRENT



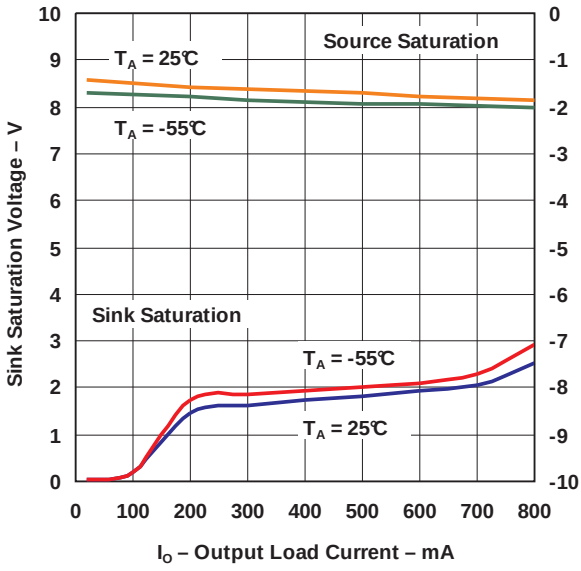
REFERENCE VOLTAGE vs TEMPERATURE



REFERENCE SHORT-CIRCUIT CURRENT vs TEMPERATURE

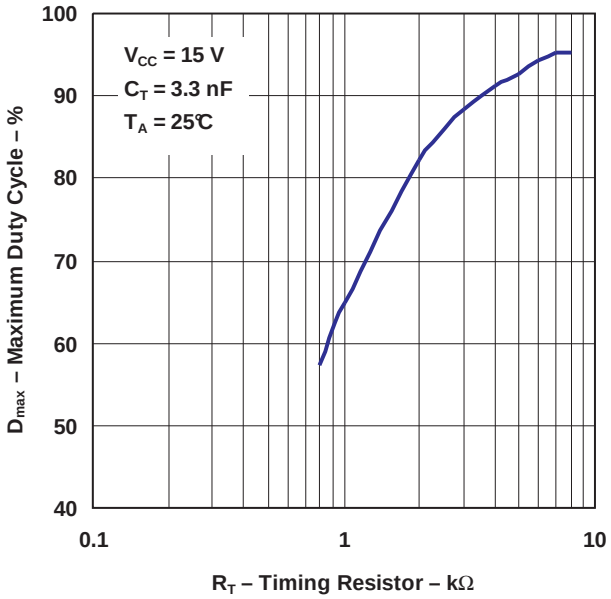


OUTPUT SATURATION VOLTAGE vs LOAD CURRENT



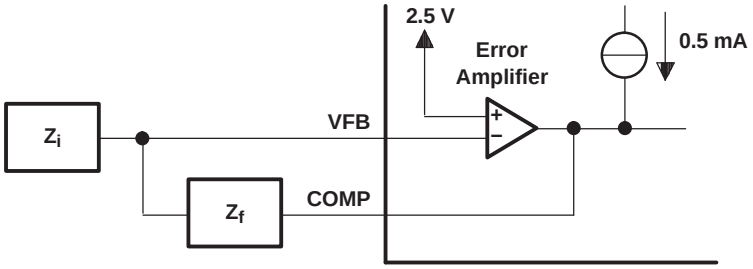
TYPICAL CHARACTERISTICS (continued)

MAXIMUM OUTPUT DUTY CYCLE
vs
TIMING RESISTOR



APPLICATION INFORMATION

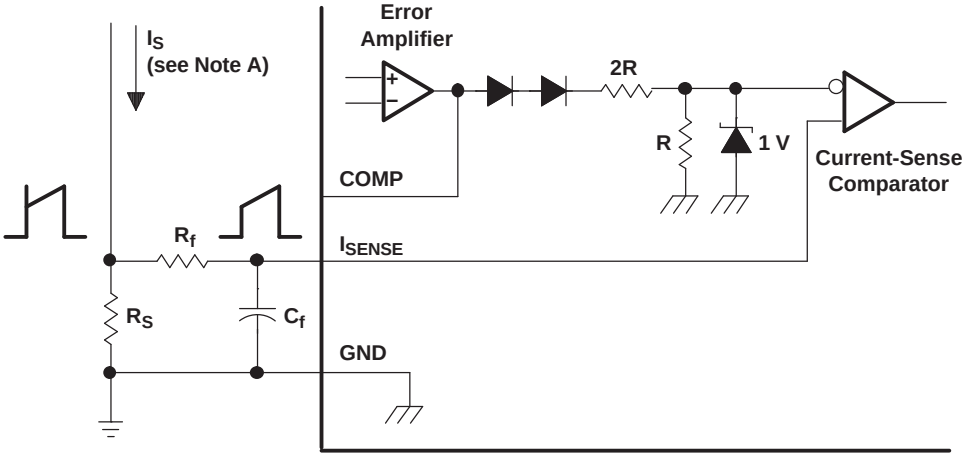
The error-amplifier configuation circuit is shown in Figure 1.



A. Error amplifier can source or sink up to 0.5 mA.

Figure 1. Error-Amplifier Configuration

The current-sense circuit is shown in Figure 2.



A. Peak current (I_S) is determined by the formula: $I_{S(max)} = 1\ V/R_S$

B. A small RC filter formed by resistor R_f and capacitor C_f may be required to suppress switch transients.

Figure 2. Current-Sense Circuit

The oscillator frequency is set using the circuit shown in Figure 3. The frequency is calculated as:

$$f = 1 / R_T C_T$$

For $R_T > 5\ k\Omega$:

$$f \approx 1.72 / R_T C_T$$

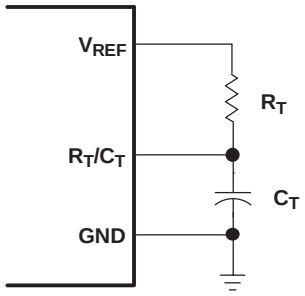
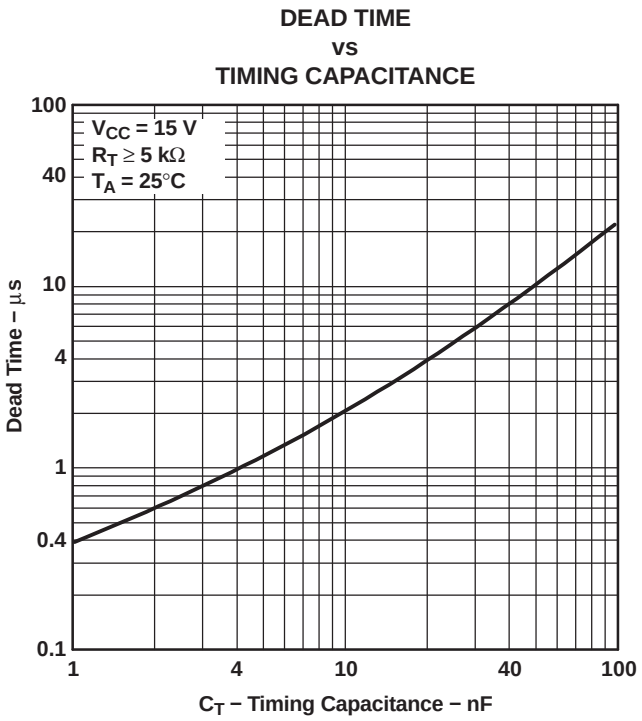
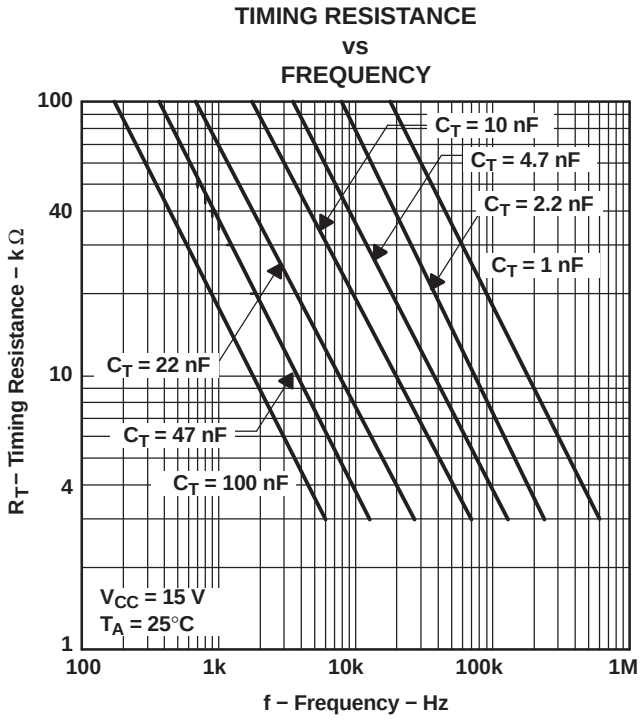


Figure 3. Oscillator Section





Open-Loop Laboratory Test Fixture

In the open-loop laboratory test fixture (see Figure 4), high peak currents associated with loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to the GND terminal in a single-point ground. The transistor and 5-kΩ potentiometer sample the oscillator waveform and apply an adjustable ramp to the I_{SENSE} terminal.

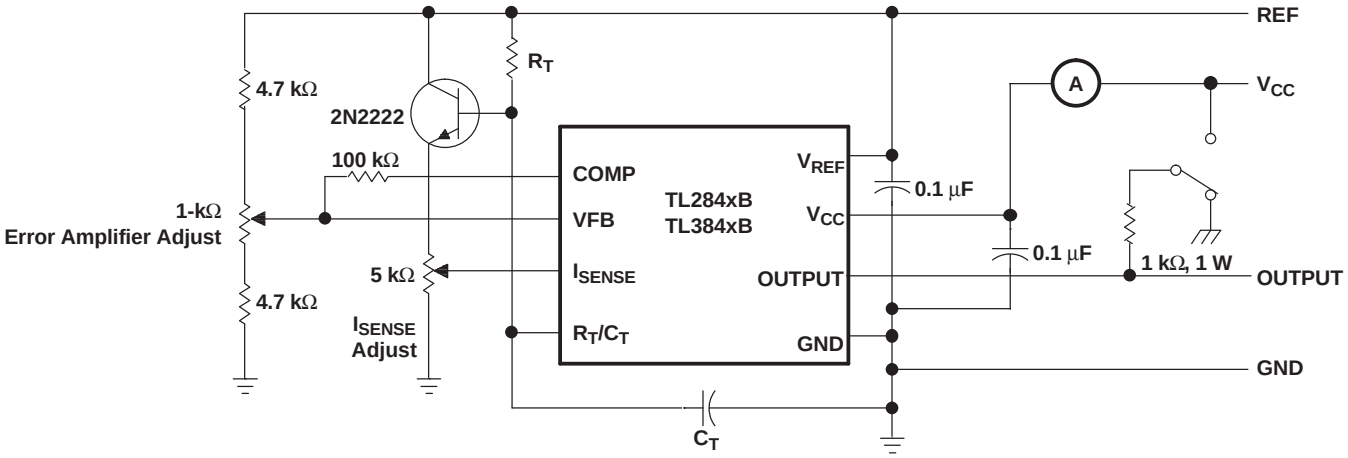


Figure 4. Open-Loop Laboratory Test Fixture

Shutdown Technique

The PWM controller (see Figure 5) can be shut down by two methods: either raise the voltage at I_{SENSE} above 1 V or pull the COMP terminal below a voltage two diode drops above ground. Either method causes the output of the PWM comparator to be high (see the *Functional Block Diagram*). The PWM latch is reset dominant so that the output remains low until the next clock cycle after the shutdown condition at the COMP or I_{SENSE} terminal is removed. In one example, an externally latched shutdown can be accomplished by adding an SCR that resets by cycling V_{CC} below the lower UVLO threshold. At this point, the reference turns off, allowing the SCR to reset.

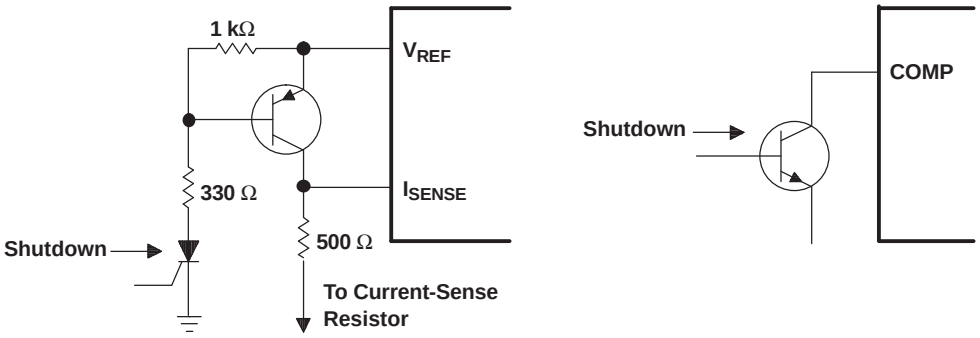


Figure 5. Shutdown Techniques

A fraction of the oscillator ramp can be summed resistively with the current-sense signal to provide slope compensation for converters requiring duty cycles over 50% (see Figure 6). Note that capacitor C forms a filter with R2 to suppress the leading-edge switch spikes.

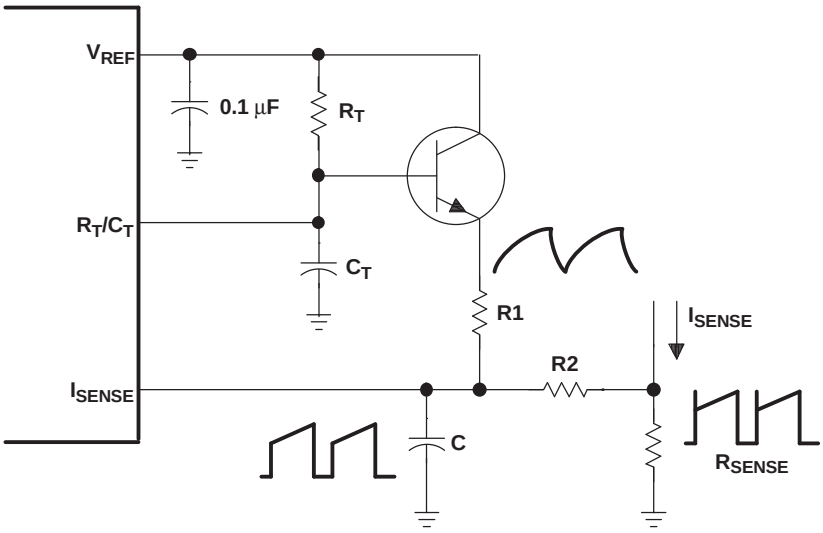


Figure 6. Slope Compensation

REVISION HISTORY

Changes from Original (July 2012) to Revision A **Page**

- Changed the pinout from an 8-pin to 14-pin D package 1
- Changed the Functional Block diagram pin numbers for the 14-pin D package 2

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL2843BQDRQ1	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL2843BQ	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

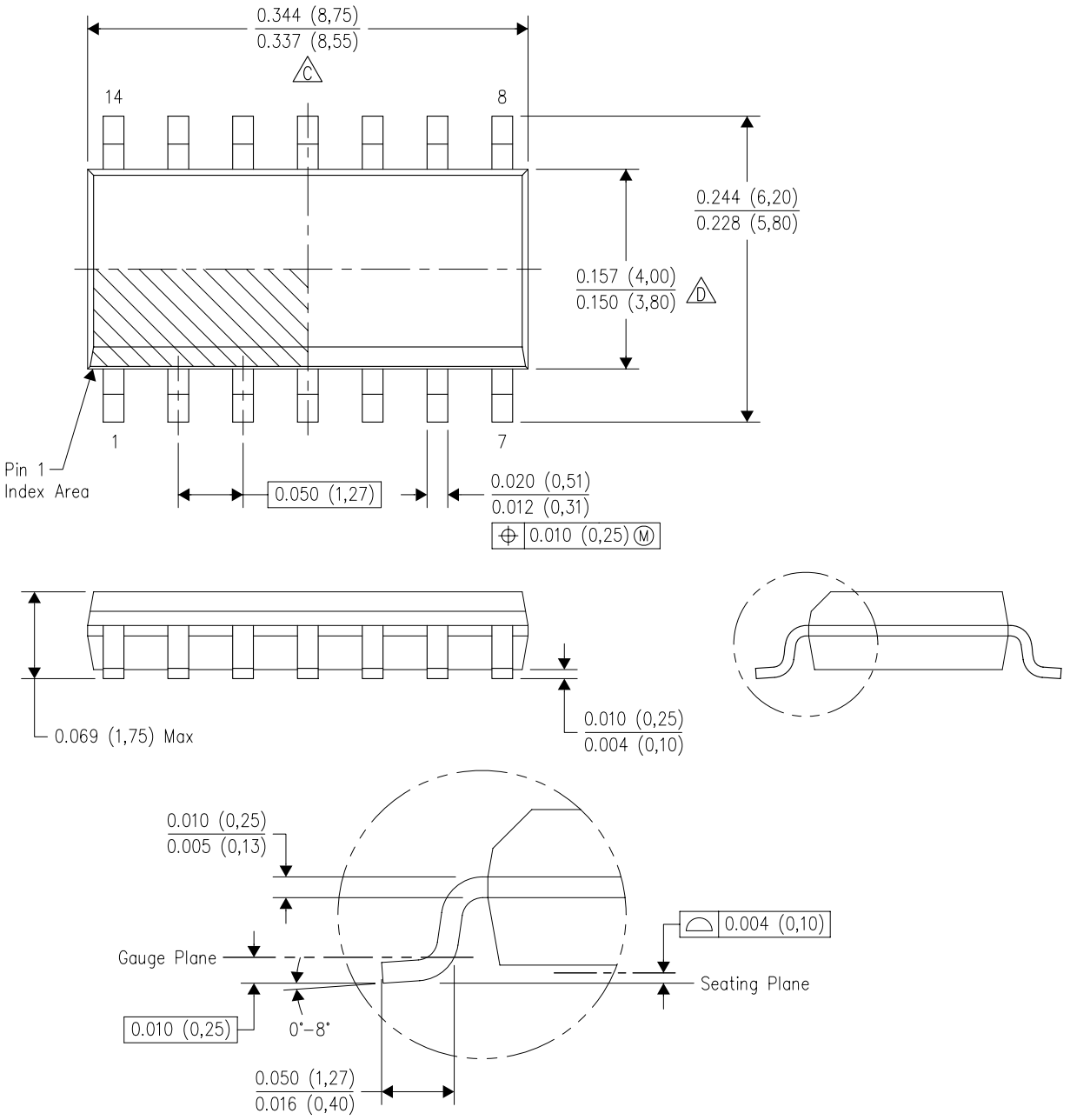
OTHER QUALIFIED VERSIONS OF TL2843B-Q1 :

- Catalog: TL2843B

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

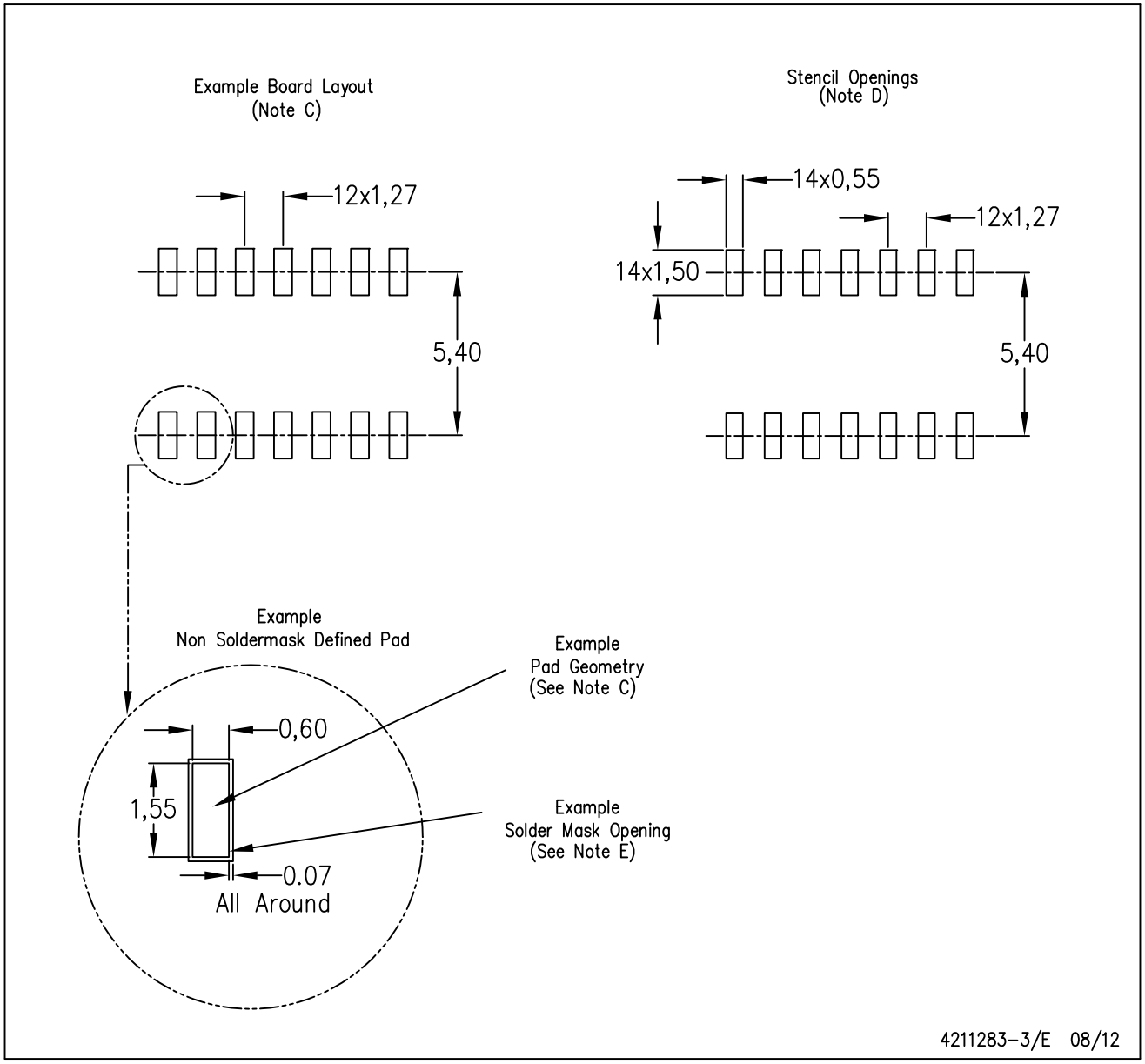
D (R–PDSO–G14) PLASTIC SMALL OUTLINE



4040047–5/M 06/11

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AB.

D (R–PDSO–G14) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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